Unitized Semiconductor Devices - Page 1 of 1



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	re Material:
Ceramic	
Overall	Length:
Betweer	n 0.660 inches and 0.785 inches
Overall	Height:
0.200 in	ches
Overall	Width:
0.325 in	ches
Compo	nent Name And Quantity:
4 transis	stor
Mountir	ng Method:
Press fit	
Feature	s Provided:
Hermeti	cally sealed case
Semico	nductor Material:
Silicon a	all transistor
Voltage	Rating In Volts Per Characteristic:
30.0 co	llector to emitter voltage/static/base open all transistor and 60.0 collector to base voltage, dc all transistor and 5.0 emitter to base
voltage,	dc all transistor
Current	Rating Per Characteristic:
300.00 r	milliamperes source cutoff current all transistor
Power F	Rating Per Characteristic:
4.6 watt	s small-signal input power, common-collector absolute all transistor
Maximu	Im Operating Tempurature Per Measurement Point:
200.0 de	egrees celsius ambient air
Termina	al Type And Quantity:
14 unins	sulated wire lead
Shelf Li	ife:
N/a	
Unit Of	Measure:
Demilita	arization:
No	
Fiig:	